A New Ultra Low-Power and Noise Tolerant Circuit Technique for CMOS Domino Logic

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Abstract— Dynamic logic style is used in high performance circuit design because of its fast speed and less transistors requirement as compared to CMOS logic style. But it is not widely accepted for all types of circuit implementations due to its less noise tolerance and charge sharing problems. A small noise at the input of the dynamic logic can change the desired output. Domino logic uses one static CMOS inverter at the output of dynamic node which is more noise immune and consuming very less power as compared to other proposed circuit. In this paper we have proposed a novel circuit for domino logic which has less noise at the output node and has very less power-delay product (PDP) as compared to previous reported articles. Low PDP is achieved by using semi-dynamic logic buffer and also reducing leakage current when PDN is not conducting. This paper also analyses the PDP of the circuit at very low voltage and different W/L ratio of the transistors.

Keywords— Dynamic logic, domino logic, Delay, diode-footed domino, noise tolerance, power consumption, robustness, technology scaling, semi-dynamic logic

I. Introduction

The rapid advancement in VLSI circuit is due to increased use of portable and wireless systems with low power budgets and microprocessors with higher speed. To achieve this, the size of transistors and supply voltages are scaled down along with technology. Due to larger number of devices per chip the interconnection density increases. The interconnection density along with high clock frequency increases capacitive coupling of the circuit. Therefore, noise pulses known as crosstalk are generated leading to logic failure and delay of the circuit [1]. Again, when supply voltage is scaled, threshold voltage of the device needs to be scaled to preserve the circuit performance, which in turn leads to increase in the leakage current of the device. Due to high speed and low device count especially compared to complementary CMOS, dynamic-logic circuits are used in a wide variety of applications including microprocessors, digital signal processors and dynamic memory[2]. Dynamic circuit contains a pulldown network (PDN) which realizes the desired logic function. According to the basic theory, the dynamic logic circuit will precharge at every clock cycle.

Due to the high frequency of the clock signal a lot of extra noise is introduced in the circuit that consumes additional power and slows down the circuit. In this paper we propose a new circuit technique which can reduce the noise of dynamic logic dramatically. This circuit increases speed and decreases the power dissipation of the circuit as compared to other domino logic styles.

II. PROBLEM STATEMENT

Figure 1 is an example of footless domino gate. During the precharge phase when the clock is LOW, the pre-charging PMOS gets ON and the dynamic node is connected to the VDD and gets precharge to VDD. When clock goes high, the evaluation phase starts and the output gets evaluated with the pull-down network and conditionally gets discharged if any one of the input is at logic 1. At the evaluation period when all the inputs are at logic 0, the dynamic node should be at logic 1. But the wide fan-in NMOS pull-down leaks the charge stored in the capacitance at the dynamic node due to the subthreshold leakage. This is again compensated by the PMOS keeper, which aims to restore the voltage of the dynamic node. When a noise voltage impulse occurs at ant gate input, the keeper may not be able to restore the voltage level of the dynamic node. The subthreshold leakage current is exponentially dependent upon V_{GS} . So in the presence of noise impulse the gate voltage increases, which leads to increase in V_{GS} and the dynamic node gets wrongly discharged. As noise of domino gates is now more important than the area, energy dissipation and delay issues, so recently several techniques have been proposed [6,7] to reduce the noise of dynamic circuits. All the techniques have reduced the noise sensitivity but there are many drawbacks with area, power dissipation and delay.

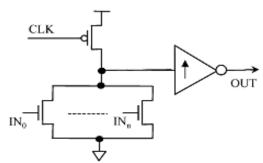


Figure 1. A typical footless Domino OR gate



III. BACKGROUND AND RELATED WORK

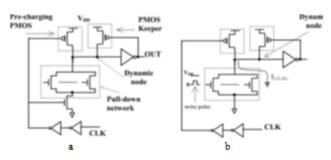


Figure 2. Standard domino OR gate a Footed scheme b Footless scheme

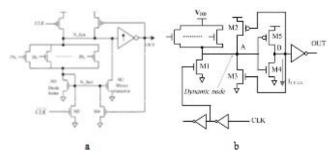


Figure 3. Previous works showing OR gate a. Diode footed Domino [6] b. Domino circuit in scheme [7]

To compensate the leakage current at the dynamic node a week transistor called keeper transistor is used. Keeper transistor prevents the charge loss and keeps the dynamic node at strong high when PDN is OFF. In the first domino proposal [3] the gate of the keeper transistor is tied to ground, therefore the keeper is always on. If at the beginning of evaluation the pull-down network (PDN) turns on, the dynamic node tends to discharge through the PDN. However, the keeper is injecting charge to the dynamic node as it is always on. This is called contention. Furthermore, a potential DC power consumption problem is generated. To alleviate the potential DC power consumption problem a feedback keeper was proposed in Figure. 2a [4, 5]. In [6], this Diode-Footed domino an NMOS transistor is there in a diode configuration i.e. gate and drain terminals connected together in series with the evaluation network, as shown in Figure 3a. A diode connected transistor is exploited in this design in which the leakage flowing through the PDN in the evaluation phase causes the voltage drop across the diode transistor. Which makes the V_{GS} negative and leakage reduces. The performance degradation can be compromised by the mirror network. By varying the size of mirror, noise immunity can be made. But when we compare it with standard footless domino this scheme is very slow. Also the inverse clock increases the capacitive load of the clock driver. In [7], the circuit based on a pull up network constitutes only the NMOS transistors as depicted in Figure 3b. This style doesn't have precharge PMOS transistors. When the clock is low i.e. at the precharge stage M1 is switched on the dynamic node is pre-charged to 0 V. When clk is high i.e. at evaluation phase M₁ is off and the pull up network conditionally can charge the dynamic node. When one or more input signals are there the dynamic node has to charge up to $V_{\rm DD}$, but due to the absence of pull up network it only charges to $V_{\rm DD}$ - $V_{\rm TH}$. This drop is compensated by the PMOS M_2 . The noise is decreased by NMOS pull up network also the leakage thru pull up network charge dynamic node. But again it needs an inverting clock which increases the capacitive load. Also it uses extra inverter like structure which increases the area and complexity of circuit.

IV. PROPOSED SCHEME

A. Circuit Analysis:-

The proposed novel domino circuit scheme is shown in Figure 4. Transistor M_4 is used as stacking transistor. Due to voltage drop across M_4 , gate-to-source voltage of the NMOS transistor in the PDN decreases (stacking effect [10]). The proposed circuit differs from [6] as it has additional evaluation transistor M5 with gate connected to the CLK. In [6], when M_4 has voltage drop due to presence of noise-signals, M_3 starts leaking that causes the circuit to dissipate power and also makes it less noise robust. The purpose of M_5 in proposed scheme causes the stacking effect and makes gate-to-source voltage of M_3 smaller (M_3 less conducting). Hence circuit becomes more noise robust and less leakage power consuming. But for performance degrades because of stacking effect in mirror current path. This can be increased by widening the M_3 (high W/L) to make it more conducting.

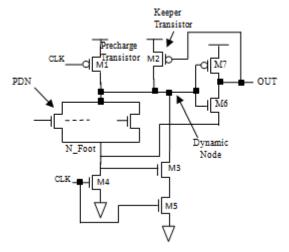


Figure 4. Proposed Circuit

B. Noise Analysis:-

When the PDN is OFF and the N_Dyn is at high voltage and the N_Foot is at low voltage. The high level of dynamic node makes the gate of the NMOS M6 of the buffer V_{DD} and the low level of N_Foot makes the source of the M_6 to 0. This makes M_6 ON and the voltage of buffer output will be same as the voltage of N_Foot. It can be easily verified that if the NMOS transistor of the buffer can always be turned off, the pulses propagating to the output can be avoided [8].



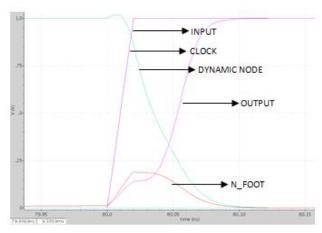


Figure 5. Simulated waveform of proposed scheme



Figure 6. Waveform simulated for the OR gate

- 1. Clock Input
- 2. Input A
- $3. \ Input \ B$
- 4. Output for basic circuit
- 5. Output for [6]
- 6. Output for [7]
- 7. Output for Proposed circuit

In the evaluation period, when the NMOS clock transistor M_4 is ON, N_Foot gets discharged to 0. When the PDN is ON the N_Dyn also gets discharged to ground. This makes the V_{CS} of buffer NMOS M_6 to 0 as $V_{CS} = V_G - V_S = 0$. This makes the NMOS OFF and the buffer output gets completely charged through PMOS M_7 . During precharge the dynamic node will get charged to high, when the PDN is ON the voltage of the N_Foot is nearly same as N_Dyn, as the NMOS M_4 is OFF. The V_{CS} of the buffer NMOS will be $V_G - V_S < V_{TH}$ which keeps the NMOS of the buffer at turned OFF stage. The PMOS of the buffer is also OFF due to the high level of N_Dyn node. This makes the output of buffer LOW.

C. Power Analysis:-

The proposed structure uses the semi-dynamic buffer structure. So the output node OUT has no pulses in the precharge stage as shown in Figure 6. In the figure the 1st waveform shows the clock the second and third wave form shows the inputs of the 2 inputs or gate. The 4th waveform shows the output plotted for the basic domino gate. The 5th and 6th waveform shows the outputs of the two reference circuit structures. The last or the 7th waveform shows the output of the proposed circuit. It can be seen that the 4, 5 and 6 waveforms contains the pulses in the precharge period, but the proposed output does not contain such pulses, which means the buffer does not get on and off frequently, so the current through the buffer reduced sufficiently then the counterpart. If there many pulses the buffer gets ON and OFF frequently. The power consumption of the logic circuit in conventional circuit is given by [8]

$$P_{avg1} = K.V_{DD}^{2}.C_{dyn} + r.f.V_{DD}.V_{noise}.C_{dyn}$$
 (1)

In which, $r = T_{on}/(T_{on}+T_{off})$;

 T_{on} is the time when input logic is on,

 T_{off} is the time when input logic is off.

K is the probability of the state that the input logic change in a unit time.

 $\boldsymbol{C}_{\scriptscriptstyle dyn}$ is the capacitor in node $\boldsymbol{N}_{\scriptscriptstyle -} dyn$

V_{noise} is the pulse in node N_dyn

Power consumption of the buffer in conventional stage is given by

$$P_{avg2} = K.V_{DD}^{2}.(C_{load} + C_{buffer}) + r.f.V_{DD}.V_{noise}.(C_{load} + C_{buffer})$$
(2)

As Cloud > Chuffer, equation 2 becomes

$$P_{avg2} = K.V_{DD}^{2}.C_{load} + r.f.V_{DD}.V_{noiss}.C_{load}$$
(3)

$$P_{\text{avg}} = \text{K.V}_{DD}^{2} \cdot \left(C_{load} + C_{dyn} \right) + r. f. V_{DD} \cdot V_{noise} \cdot \left(C_{load} + C_{dyn} \right) \tag{4}$$

In the proposed logic the power is given by

$$P_{prop} = K.V_{DD}^{2}.C_{load} + r.f.V_{DD}.V_{noise_p}.C_{load}$$
 (5)

So the finally the amount of power which the proposed circuit saves is

$$\begin{aligned} & \mathbf{P_{avg}} - \mathbf{P_{prop}} = \mathbf{K}.V_{DD}^{\ 2}.\left(C_{load} + C_{dyn}\right) + r.f.V_{DD}.V_{noise}.\left(C_{load} + C_{dyn}\right) - \mathbf{K}.V_{DD}^{\ 2}.C_{load} - r.f.V_{DD}.V_{noise_p}.C_{load} \end{aligned}$$

Power saved due to semidynamic logic is

$$\begin{split} P_{saved} &= \text{K.} V_{DD}^{2}. C_{dyn} + r.f. V_{DD}. V_{noise}. C_{dyn} + \\ r.f. V_{DD}. V_{noise}. C_{load} \end{split} \tag{6}$$

As
$$V_{noise} \gg V_{noise}$$
.



TABLE: I POWER DELAY COMPARISON OF THE PROPOSED CIRCUIT WITH PREVIOUS REPORTED ARTICLES

| Supply Voltage in Volt | Parameters | Basic Domino Footless and Keeperless | Basic Domino Footless and with Keeper | Basic Domino Footed and with Keeper | Scheme on Paper [6] | Scheme on paper [7] | Proposed Scheme |
|---------------------------|------------|--|---|---|------------------------|------------------------|--------------------|
| 1 | Delay | 1.57 E-11 | 2.40 E-11 | 4.109 E-8 | 1.23 E-9 | 1.04 E-9 | 3.3 E-11 |
| | Power | 3.33 E-5 | 3.32 E-5 | 5.6 E-6 | 4.58 E-5 | 5.6 E-8 | 1.42 E-8 |
| 0.9 | Delay | 1.78 E-11 | 2.69 E-11 | 4.10 E-8 | 1.28 E-9 | 1.05 E-9 | 3.86 E-11 |
| | Power | 2.39 E-5 | 2.39 E-5 | 9.6 E-6 | 3.20 E-5 | 8.58 E-8 | 1.56 E-8 |
| 0.8 | Delay | 2.08 E-11 | 3.13 E-11 | 4.111 E-8 | 1.32 E-9 | 1.06 E-9 | 4.64 E-11 |
| | Power | 1.62 E-5 | 1.62 E-5 | 2.8 E-5 | 2.20 E-5 | 1.49 E-8 | 4.80 E-8 |
| 0.7 | Delay | 2.52 E-11 | 3.82 E-11 | 4.00 E-8 | 1.35 E-9 | 1.09 E-9 | 5.89 E-11 |
| | Power | 1.01 E-5 | 1.01 E-5 | 1.14 E-5 | 1.39 E-5 | 1.39 E-8 | 3.10 E-8 |
| 0.6 | Delay | 3.29 E-11 | 5.04 E-11 | 4.01 E-8 | 1.42 E-9 | 1.15 E-9 | 6.10 E-11 |
| | Power | 5.56 E-6 | 5.56 E-5 | 1.4 E-5 | 7.81 E-5 | 1.44 E-8 | 2.37 E-8 |
| 0.5 | Delay | 4.90 E-11 | 7.73 E-11 | 4.16 E-8 | 1.58 E-9 | 1.31 E-9 | 1.28 E-10 |
| | Power | 2.44 E-6 | 2.46 E-5 | 1.4 E-5 | 3.50 E-5 | 3.1 E-8 | 5.55 E-8 |

TABLE: II POWER-DELAY-PRODUCT COMPARISON OF THE PROPOSED CIRCUIT WITH PREVIOUS REPORTED ARTICLES

| Supply Voltage in Volt | Basic Domino Footless and Keeperless | Basic Domino Footless and with Keeper | Basic Domino Footed and with Keeper | Scheme on Paper [6] | Scheme on paper [7] | Proposed Scheme |
|---------------------------|--|---|---|------------------------|------------------------|-----------------|
| 1 | 5.23E-16 | 7.97E-16 | 2.3E-13 | 3.94E-14 | 5.82E-17 | 4.69E-19 |
| 0.9 | 4.25E-16 | 6.43E-16 | 3.94E-13 | 4.1E-14 | 9.01E-17 | 6.02E-19 |
| 0.8 | 3.37E-16 | 5.07E-16 | 1.15E-12 | 2.9E-14 | 1.58E-17 | 2.23E-18 |
| 0.7 | 2.55E-16 | 3.86E-16 | 4.56E-13 | 1.88E-14 | 1.52E-17 | 1.83E-18 |
| 0.6 | 1.83E-16 | 2.8E-15 | 5.61E-13 | 1.11E-13 | 1.66E-17 | 1.45E-18 |
| 0.5 | 1.2E-16 | 1.9E-15 | 5.82E-13 | 5.53E-14 | 4.06E-17 | 7.1E-18 |

V. SIMULATION AND COMPARISON OF RESULTS

The circuits were simulated with using Cadence Specter using 90 nm technology using 1 V. The circuit was being compared with the OR gate previous techniques. The OR gate was implemented because it is a typical example of wide pull-down network. The proposed circuit was being implemented for OR gate and being compared with the OR gate of other reference circuits and also investigated with different values of fan-in. It was found that the proposed circuit performs better than the previous proposed circuits.

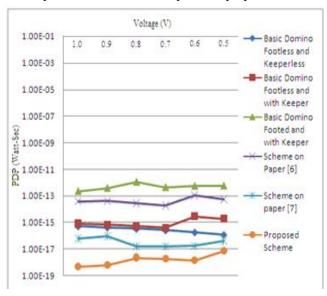


Figure 7. PDP Plot for the proposed scheme with the other schemes by reducing V_{DS} from 1 V to 0.5 mV

TABLE III. COMPARASION OF THE PROPOSED CIRCUIT BY NUMBER OF TRANSISTORS

| Circuit type | Scheme on Paper [6] | Scheme on paper [7] | Proposed Scheme |
|------------------------------------|------------------------|------------------------|--------------------|
| Number of Extra transistor used | 12 | 11 | 9 |
| Use of Inverting clock | Yes | Yes | No |

The PDP (Power-Delay Product) was calculated and simulated plotted using cadence spectre. Table 1 shows the power and delay of all the reference circuits, the basic circuits and the proposed circuit. Table 2 compares the power-delay product of the circuits. When compared to the other circuits it can be seen that the PDP can be reduced 100 times in the proposed circuit. This can also be viewed in the graph shown in figure 7. The proposed circuit shows advantage in having less number of transistors as compared to the previous Table 3. As compared to the basic domino the proposed circuit contains only 3 extra transistors where the other circuits contain more number of extra transistors with the disadvantage of having the inverting clock. The performance of the proposed circuit was checked by changing the size of the extra transistors used for increasing the circuit performance. The size of M3, M4 and M5 were decreased below 1 up to 0.1 and increased from 1 to 10. With this variation the outputs were calculated and graphs were plotted. It can be observed that the circuit responds more to the variation in M4, which is having more sloped then others. The circuit gives better performance when W/L ratio is closed to 1. PDP increases by increasing the size of M5. So the PDP performance of the circuit can be increased by decreasing the size of M5.



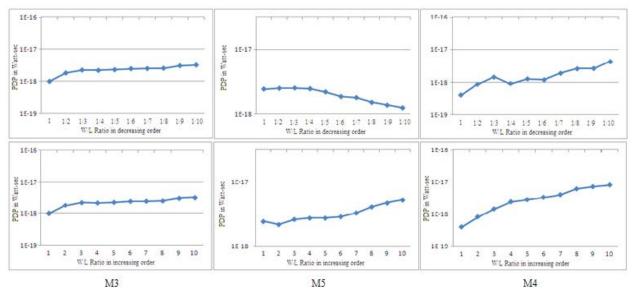


Figure 8. PDP Plot for the proposed scheme by varying the W/L ratio for M3, M4 and M5 for W/L decreasing from 1 to 1/10 and increasing from 1 to 10

It can also be observed that the circuit gives better performance when W/L ratio is closed to 1. So it can be concluded that by changing the W/L ratio of the transistors the performance of the circuit can further be increased in terms of speed and power dissipation.

VI. CONCLUSION

In this paper, we have proposed a high-speed and low-power domino logic circuit, which also have noise-tolerance in the output node. The simulation was done with 90 nm and 1 V CMOS process. The results have shown that the proposed scheme can work with very high speed and also consuming very low power, which reduces the PDP of the circuit exponentially. Proposed circuit also shows noise efficiency because the noise of the output buffer dramatically improved as compared to previous work. Also the circuit is flexible for wide variety of dynamic logic styles and adequate for large fan-in gates.

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REFERENCES

- [1] F. Mendoza-Hernandez, M. Linares-Aranda and V. Champac, "Noise tolerant improvement in dynamic CMOS logic circuit", IEEE Proc.-Circuits Devices Systems, Vol 153, No. 6, Dec 2006, pp.. 565-573
- [2] H.L. Yeager et al, "Domino Circuit Topology", U. S. Patent 6784695, Aug. 31, 2004.

- [3] Krambeck, R.H., Lee, C. M., and Stephen Law, H.-F., "High-speed compact circuits with CMOS", IEEE J. Solid-State Circuits, 1982, 17, (3), pp. 614–619
- [4] Oklobdzija, V.G., and Montoye, R.K., "Design-performance tradeoffs in CMOS domino logic". Proc. IEEE Conf. on Custom Integrated Circuits, May 1985, pp. 334–337
- [5]Oklobdzija, V.G., and Montoye, R.K.,"Design-performance tradeoffs in CMOS-domino logic", IEEE J. Solid-State Circuits, 1986, 21, (2), pp. 304–306
- [6] Mahmoodi-Meimand H., Roy K.: 'Diode-footed domino: a leakage-tolerant high fan-in dynamic circuit design style', IEEE Trans. Very Large Scale Integr. Syst., 2004, 51, (3), pp. 495–503 [7] Frustaci F., Corsonello P., Cocorullo G.: 'A new noise-tolerant dynamic logic circuit design', IEEE Ph.D. Research in Microelectronics and Electronics, PRIME 2007, Bordeaux, France, July 2007, pp. 61–64
- [8] Fang Tang, Ke Zhu, Quan Gan and Jian Guo Tang, "Low-noise and power dynamic logic circuit design based on semi-dynamic logic", Anti-counterfeiting, Security and Identification, 2008. ASID 2008. 2nd International Conference on 20-23 Aug. 2008, pp 20-23 [9] Atila Alvaizdpoul, Per Lurssoia-Edefors and Christer Sveizsson, "A Leakage-Tolerant Multi-Phase Keeper For Wide Domino Circuits," Proceedings of ICECS '99. The 6th IEEE International Conference on Electronics, Circuits and Systems, pp.209, 1999. [10] Kiat-Seng Yeo, Kaushik Roy, "Low-voltage low-power voltage subsystems" Tata Mc-Graw-Hill edition 2009.
- [11] http://ptm.asu.edu/modelcard/2006/45nm_bulk.pm
- [12] R. J.-H. Sung, D. G. Elliott, "Clock-Logic Domino Circuits for High-Speed and Energy-Efficient Microprocessor Pipelines," IEEE Transactions on Circuits and Systems II: Express Briefs, Vol.54(5), pp.460, May 2007.
- [13] V. Sharma, W.K. Al-Assadi, "Analysis and Modeling of Crosstalk Noise in Domino CMOS Circuits," IEEE Region 5 Technical Conference, pp.374, April 2007.
- [14] Song Jia, Fei Liu, Jun Gao, Ling Liu, Xinan Wang, Tianyi Zhang, Zhongjian Chen, Lijiu Ji, "A 64-bit lookahead carry chain in Inverted-Domino logic," IEEE Conference on Electron Devices and Solid-State Circuits, pp.281, Dec. 2003.

